

CHEMICAL SENSOR PACKAGE FOR HIGHLY PRESSURED ENVIRONMENT

FIELD OF THE INVENTION

[0001] The invention relates to chemical sensor package. More specifically, the invention relates to chemical sensor package for high pressure environment.

BACKGROUND

[0002] Chemical sensors have been used for several areas such as laboratorial or industrial testing and oceanic scientific expedition or oil prospecting. Also, additional encapsulation and packaging is typically required depending on the intended use and application environments.

[0003] In some environment such as oceanic applications, high pressure is applied to the chemical sensors and packaging for protecting the chemical sensors from high pressure environment is necessary. For instance, at 3 km below deep sea application, pressure could be increased to 20kpsi (138 MPa). For the sensor application under such a highly pressurized condition, the pressure differential between the external environment and internal structure of the sensor can be substantial. Existing packaging solutions are unable to withstand such a high pressure difference, limiting their usage for such a high pressure environment.

[0004] Thus, what is needed is an improved chemical sensor package that withstands a highly pressurized condition. Furthermore, other desirable features and characteristics will become apparent from the subsequent detailed description and the appended claims, taken in conjunction with the accompanying drawings and this background of the disclosure.

SUMMARY

[0005] In a first aspect of the present invention, a package for a chemical sensor including an encapsulation and a pressure balancing structure is disclosed. The encapsulation encapsulates a chemical sensor and has a hole for exposing a chemical sensitive part of the chemical sensor. The pressure balancing structure balances pressure applied to the chemical sensor at the chemical sensitive part.

[0006] In a second aspect of the present invention, a method for packaging a chemical sensor is disclosed. The method includes encapsulating a chemical sensor; providing a hole for exposing a chemical sensitive part of the chemical sensor; and providing a pressure balancing structure for balancing pressure applied to the chemical sensor at the chemical sensitive part.

[0007] In a third aspect of the present invention, a pressure resistant chemical sensor including a chemical sensor, an encapsulation and a pressure balancing structure is disclosed. The encapsulation encapsulates the chemical sensor and has a hole for exposing a chemical sensitive part of the chemical sensor. The pressure balancing structure balances pressure applied to the chemical sensor at the chemical sensitive part.

BRIEF DESCRIPTION OF THE DRAWINGS

[0008] The accompanying figures, where like reference numerals refer to identical or functionally similar elements throughout the separate views and which together with the detailed description below are incorporated in and form part of the specification, serve to illustrate various embodiments and to explain various principles and advantages in accordance with the present embodiment.

[0009] FIG. 1 depicts a chemical sensor package with pressure balancing hole in accordance with a present embodiment.

[0010] FIG. 2 depicts a chemical sensor package with pressure balancing supporting structure in accordance with a present embodiment.

[0011] FIG. 3, comprising FIG. 3a to FIG. 3c, illustrates simulation models of a bending stress under high pressure loading condition, wherein FIG. 3a illustrate conventional chemical sensor package, FIG. 3b illustrates a chemical sensor package with pressure balancing hole in accordance with a present embodiment and FIG. 3c illustrates a chemical sensor package with pressure balancing supporting structure in accordance with a present embodiment.

[0012] FIG. 4 depicts a flowchart of a method for packaging a chemical sensor in accordance with a present embodiment.

[0013] FIG. 5 depicts a detailed packaging flow in accordance with a present embodiment.

[0014] Skilled artisans will appreciate that elements in the figures are illustrated for simplicity and clarity and have not necessarily been depicted to scale. For example, the dimensions of some of the elements in the simulation visualization or steps in the flowcharts may be exaggerated in respect to other elements to help improve understanding of the present embodiment.

DETAILED DESCRIPTION

[0015] The following detailed description is merely exemplary in nature and is not intended to limit the invention or the application and uses of the invention. Furthermore, there is no intention to be bound by any theory presented in the preceding background of the invention or the following detailed description. It is the intent of the present embodiment to present an improved chemical sensor package that withstands in high pressure environment.

[0016] FIG. 1 depicts a chemical sensor package 100 with pressure balancing hole 108 in accordance with a present embodiment. The chemical sensor package 100 encapsulates chemical sensor 102 by encapsulation 116. However, chemical sensitive layer 104 of chemical sensor 102 is exposed for sensing purpose. When the chemical sensor 102 is under highly pressurized environment, the chemical sensor 102 receives high pressure 106 at the exposed part, i.e. chemical sensitive layer 104. Conventional chemical sensor package without pressure balancing structure is unable to withstand such a high pressure 106.

[0017] The chemical sensor package 100 in accordance with a present embodiment has pressure balancing hole 108 to withstand the high pressure 106 by applying counter pressure 110 to the chemical sensor 102 from opposite side of the chemical sensor. Since both sides of the chemical sensor 102 are in direct contact with high pressure environment, the pressure differential experienced by conventional chemical sensor package without pressure balancing structure will be eliminated.

[0018] In addition, the chemical sensor package 100 includes a conformal coating 112 for protecting the chemical sensor package 100. The conformal coating 112 may be hydrophobic conformal coating for use in e.g. deep sea application. Such a waterproof coating will enhance reliability of the chemical sensor package 100.

[0019] Furthermore, the chemical sensor package 100 includes Redistribution Layer (RDL) 114 on the chemical sensor 102 for moving a wiring 120 outside of the encapsulation 116 away from the opposite side of the chemical sensitive part 104. Since RDL 114 redistributes the wiring 120, counter pressure 110 applied to the chemical sensor 102 will not interfere with the wiring 120. The chemical sensor package 100 further includes Through Mold Via (TMV) interconnection 114 for connecting the chemical sensor 102 to the wiring 120 outside of the encapsulation 116 via interconnection pad 118.

[0020] The chemical sensor package 100 is fabricated through fan-out wafer level packaging (FO-WLP) instead of fan-in wafer level packaging (FI-WLP). Enhanced design flexibility of FO-WLP enables to have a pressure balancing structure 108 within the chemical sensor package 100.

[0021] Preferably the chemical sensor 102 is an ion sensitive field effect transistor (ISFET) and the chemical sensitive layer 104 is an ion sensitive layer. Ion species detection by the ion sensitive layer is largely dependent upon the type of membrane deposited and is not restricted to detecting only pH (H^+ ion). Also the chemical sensor 102 may detect liquid or gas in accordance with appropriate chemical sensing layer 104.

[0022] FIG. 2 depicts a chemical sensor package 200 with pressure balancing supporting structure 208 in accordance with a present embodiment. The chemical sensor package 200 is similar to the chemical sensor package 100 of FIG.1. The difference is pressure balancing hole 108 is replaced by pressure balancing supporting structure 208. Counter pressure 210 for mitigating high pressure 206 on chemical sensitive layer 204 of the chemical sensor 202 will be applied to chemical sensor 202 via the pressure balancing supporting structure 208.

[0023] Similar to chemical sensor package 100 of FIG.1, the chemical sensor package 200 includes a conformal coating 212 for protecting the chemical sensor package 200. The conformal coating 112 may be hydrophobic conformal coating for use in e.g. deep sea application. Such a waterproof coating will enhance reliability of the chemical sensor package 200.

[0024] Furthermore, the chemical sensor package 200 includes Redistribution Layer (RDL) 214 on the chemical sensor 202 for moving a wiring 220 outside of the encapsulation 216 away from the opposite side of the chemical sensitive part 204. Since RDL 214 redistributes the wiring 220, counter

pressure 210 applied to the chemical sensor 202 will not interfere with the wiring 220. The chemical sensor package 200 further includes Through Mold Via (TMV) interconnection 214 for connecting the chemical sensor 202 to the wiring 220 outside of the encapsulation 116 via interconnection pad 218.

[0025] The chemical sensor package 200 is fabricated through fan-out wafer level packaging (FO-WLP) instead of fan-in wafer level packaging (FI-WLP). Enhanced design flexibility of FO-WLP enables to have a pressure balancing structure 208 within the chemical sensor package 200.

[0026] FIG. 3a, 3b and 3c depict bending stress simulation models. In the simulation models, a 20kpsi pneumatic pressure loading is applied to simulate the high pressure loading condition for deep sea environment for the estimated depth as 3km.

[0027] FIG. 3a depicts bending stress simulation model 300 of conventional chemical sensor package. The conventional chemical sensor package does not have pressure balancing structure. Due to the asymmetrical configuration, chemical sensor 302 experiences a heavy stress distortion as well as a bending stress (498 MPa) that exceeded the flexural strength of Silicon at the highly stressed point 308 by high pressure 304.

[0028] On the other hand, FIG. 3b depicts bending stress simulation model 310 of chemical sensor package with pressure balancing hole in accordance with a present embodiment. Aside from the symmetrical configuration which can eliminate stress distortion and bending on the chemical sensor 312 by cancelling high pressure 314 with counter high pressure 316, the maximum stress experienced by the chemical sensor 312 turned out to be only compressive component with low stress level (-57MPa).

[0029] Also, FIG. 3c depicts bending stress simulation model 320 of chemical sensor package with pressure balancing supporting structure in accordance with a present embodiment. Similar to FIG. 3b, high pressure 324 applied to chemical sensor 322 is cancelled by counter pressure 326. The simulation model 320 shows much lower stress level (-70MPa) than model of conventional package as shown in FIG. 3a.

[0030] FIG. 4 depicts a flowchart 400 of a method for packaging a chemical sensor in accordance with a present embodiment. In step 402, a chemical sensor is encapsulated by an encapsulation. In

step 404, a pressure balancing structure is provided. The pressure balancing structure is balancing pressure applied to the chemical sensor. In step 406, a hole is provided on the encapsulation. The hole exposes a chemical sensitive part of the chemical sensor.

[0031] FIG. 5 depicts a detailed packaging flow 500 in accordance with a present embodiment. In step (a), a chemical sensor 506 is placed on a carrier 508. Also, a chemical sensitive layer 502 of the chemical sensor 506 is covered by a cap 504 for protection.

[0032] In step (b), compression molding is applied to the chemical sensor 506 using encapsulation 510. Since cap 504 is covering chemical sensitive layer 502 of the chemical sensor 506, encapsulation 510 covers the cap 504 instead of chemical sensitive layer 502. In step (c), a carrier 508 is debonded from the chemical sensor 506 and its encapsulation 510.

[0033] And then, in step (d), Redistribution Layer (RDL) 512 is provided on the chemical sensor 506. If pressure balancing structure is a pressure balancing hole, further cap 514 is provided on the opposite side of the cap 504 so that symmetrical structure to balance pressure is achieved.

[0034] In step (e), interconnection is provided and RDL 512 is encapsulated by further encapsulation 516. In step (f), holes 518 are provided on the position of the cap 504 and the further cap 514. One of the holes 518 exposes the chemical sensitive layer 502 of the chemical sensor 506. The other hole is located the opposite side of the chemical sensor 506 and making symmetrical structure to mitigate high pressure from outside.

[0035] While exemplary embodiments have been presented in the foregoing detailed description of the invention, it should be appreciated that a vast number of variations exist. For example, those skilled in the art will realize from the teachings herein that the present technology may also be applied to any part in the other type of chemical sensors.

[0036] It should further be appreciated that the exemplary embodiments are only examples, and are not intended to limit the scope, applicability, operation, or configuration of the invention in any way. Rather, the foregoing detailed description will provide those skilled in the art with a convenient road map for implementing an exemplary embodiment of the invention. It being understood that various changes may be made in the function and arrangement of elements and method of operation described

in an exemplary embodiment without departing from the scope of the invention as set forth in the appended claims.

[0037] Reference numerals

- 100 Chemical sensor package with pressure balancing hole
- 102 Chemical sensor
- 104 Chemical sensitive layer
- 106 High pressure
- 108 Pressure balancing hole
- 110 High pressure
- 112 Hydrophobic Conformal Coating
- 114 RDL and TMV
- 116 Encapsulation
- 118 Interconnection Pads
- 120 Wiring
- 200 Chemical sensor package with pressure balancing supporting structure
- 202 Chemical sensor
- 204 Chemical sensitive layer
- 206 High pressure
- 208 Pressure balancing supporting structure
- 210 High pressure
- 212 Hydrophobic Conformal Coating
- 214 RDL and TMV
- 216 Encapsulation
- 218 Interconnection Pads
- 220 Wiring
- 300 Bending stress simulation model of conventional chemical sensor package
- 302 Chemical sensor
- 304 High pressure

- 308 Highly stressed point
- 310 Bending stress simulation model of chemical sensor package with pressure balancing hole
- 312 Chemical sensor
- 314 High pressure
- 316 High pressure
- 320 Bending stress simulation model of chemical sensor package with pressure balancing supporting structure
- 322 Chemical sensor
- 324 High pressure
- 326 High pressure
- 400 Flowchart of a method for packaging a chemical sensor
- 402 Encapsulate a chemical sensor
- 404 Provide a pressure balancing structure for balancing pressure applied to the chemical sensor
- 406 Provide a hole on encapsulation for exposing a chemical sensitive part of the chemical sensor
- 500 Detailed packaging flow
- 502 Chemical sensitive layer
- 504 Cap
- 506 Chemical sensor
- 508 Carrier
- 510 Encapsulation
- 512 Redistribution Layer (RDL)
- 514 Cap
- 516 Encapsulation
- 518 Hole

CLAIMS

What is claimed is:

1. A chemical sensor package for highly pressured environment comprising:

an encapsulation for encapsulating a chemical sensor, having a hole for exposing a chemical sensitive part of the chemical sensor; and

a pressure balancing structure for balancing pressure applied to the chemical sensor at the chemical sensitive part.
2. The package in accordance with claim 1, wherein the pressure balancing structure is a pressure balancing hole for applying counter pressure to the chemical sensor at the opposite side of the chemical sensitive part.
3. The package in accordance with claim 2, further comprising Redistribution Layer (RDL) on the chemical sensor for moving a wiring outside of the encapsulation away from the opposite side of the chemical sensitive part.
4. The package in accordance with claim 1, wherein the pressure balancing structure is a pressure balancing supporting structure for applying counter pressure to the chemical sensor at the opposite side of the chemical sensitive part.
5. The package in accordance with claim 4, further comprising Redistribution Layer (RDL) on the chemical sensor for moving a wiring outside of the encapsulation away from the opposite side of the chemical sensitive part.

6. The package in accordance with claim 5, further comprising Through Mold Via (TMV) interconnection for connecting the chemical sensor to the wiring outside of the encapsulation.
7. The package in accordance with claim 1, wherein the package is fabricated through fan-out wafer level packaging (FO-WLP) processes.
8. The package in accordance with claim 1, further comprising a hydrophobic conformal coating on the encapsulation.
9. The package in accordance with claim 1, wherein the chemical sensor is an ion sensitive field effect transistor (ISFET) sensor and the chemical sensitive part is an Ion sensitive layer.
10. A method for packaging a chemical sensor comprising:
encapsulating a chemical sensor by a encapsulation;
providing a hole for exposing a chemical sensitive part of the chemical sensor; and
providing a pressure balancing structure for balancing pressure applied to the chemical sensor at the chemical sensitive part.
11. The method in accordance with claim 10, wherein the pressure balancing structure is a pressure balancing hole for applying counter pressure to the chemical sensor at the opposite side of the chemical sensitive part, the method further comprising providing Redistribution Layer (RDL) on the chemical sensor for moving a wiring outside of the encapsulation away from the opposite side of the chemical sensitive part.
12. The method in accordance with claim 10, the pressure balancing structure is a pressure balancing supporting structure for applying counter pressure to the chemical sensor at the opposite side of the chemical sensitive part, the method further comprising providing Redistribution Layer

(RDL) on the chemical sensor for moving a wiring outside of the encapsulation away from the opposite side of the chemical sensitive part.

13. The method in accordance with claim 10, further comprising providing Through Mold Via (TMV) interconnection for connecting the chemical sensor to the wiring outside of the encapsulation.

14. The method in accordance with claim 10, wherein the package is fabricated through fan-out wafer level packaging (FO-WLP) processes.

15. The method in accordance with claim 10, further comprising coating the encapsulation by a hydrophobic conformal coating.

16. A pressure resistant chemical sensor comprising:

a chemical sensor;

an encapsulation for encapsulating the chemical sensor, having a hole for exposing a chemical sensitive part of the chemical sensor; and

a pressure balancing structure for balancing pressure applied to the chemical sensor at the chemical sensitive part.